

SINGLE AND LARGE GRAIN ACTIVITIES AT FERMI



Single Crystal Niobium Technology Workshop

Araxia, Brazil

Claire Antoine + Fermi teams...

10/31/2006



Layout



■ Large grain / Monocrystal Cavities development

- Fabrication process
- 1cell program

■ Sample R&D to support cavities fabrication

- Recrystallization study
- Cold and room temperature properties
- Magnetic properties

■ Sample R&D to understand SRF issues

- Grain boundaries and roughness
- GB and field enhancement
- GB and weak superconductivity

Collaboration with MSU

Collaboration with FSU



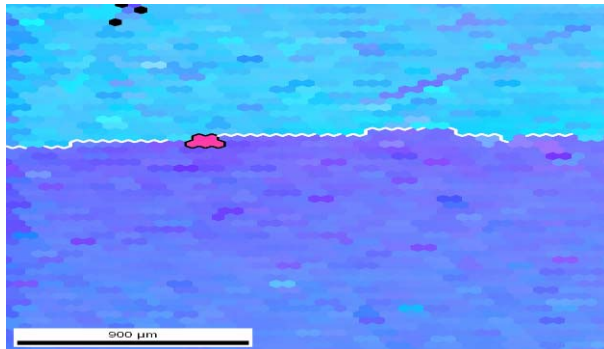
FNAL monocrystal Nb program

■ Interest :

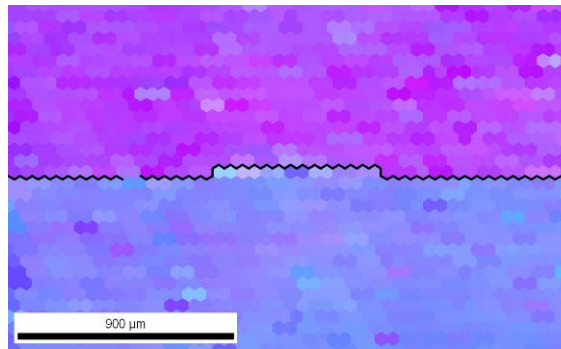
- Fewer fabrication steps => starting material should be less expensive
- No/few recrystallization @ welding => BCP instead of EP
- Possibility to choose the proper orientation for :
 - Formability ? e.g. (111) = *more favorable for small grain textures*
 - Oxygen diffusion ? (111) = *close packed* / (001) = *loose packed*
 - Oxide thickness ? (*idem*)
 - Surface B_C ? (B_{C3})
 - Recrystallization @ welding...



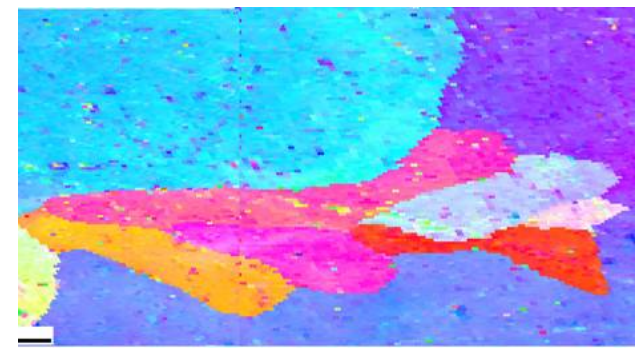
grain orientations: asymmetric ↓



symmetric ↓



triple point ↓



[H. Jiang et al, MSU]



Monocrystal Nb program...

2 complementary goals :

- Developing local expertise on the fabrication process :

- ~ 10-15 1-cell cavities project
- 3.9 GHz :
 - ✦ Easier to get 1! -grain material
 - ✦ Sufficient to determine the fabrication steps
 - ✦ Can be used to test EP, and other behaviors
 - ✦ High R_{BCS} losses => limited RF testing ?

- Then 1.3 GHz

- ✦ RF testing once the fabrication process is mastered

- R&D program on sample:

- Sensitivity of the crystalline orientation to :
 - ✦ EP vs BCP
 - ✦ Baking/Oxygen diffusion
 - ✦ Hydrogen loading
 - ✦ ...
- Bi-crystal studies... [see P. Lee talk]

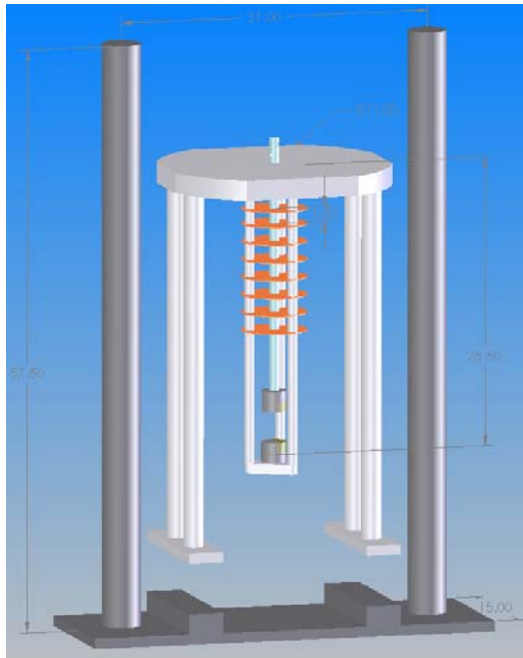




Mechanical properties: cold and RT

Tensile test from 4 K – 300 K

- Minor investment and time required
- QA: Systematic testing of Nb batches : RT and Cold mechanical properties => **data for modeling** (forming, mechanical resistance , RF behavior...)
- **Recrystallization study**





2 Priority : cold testing upgrade of the Instron

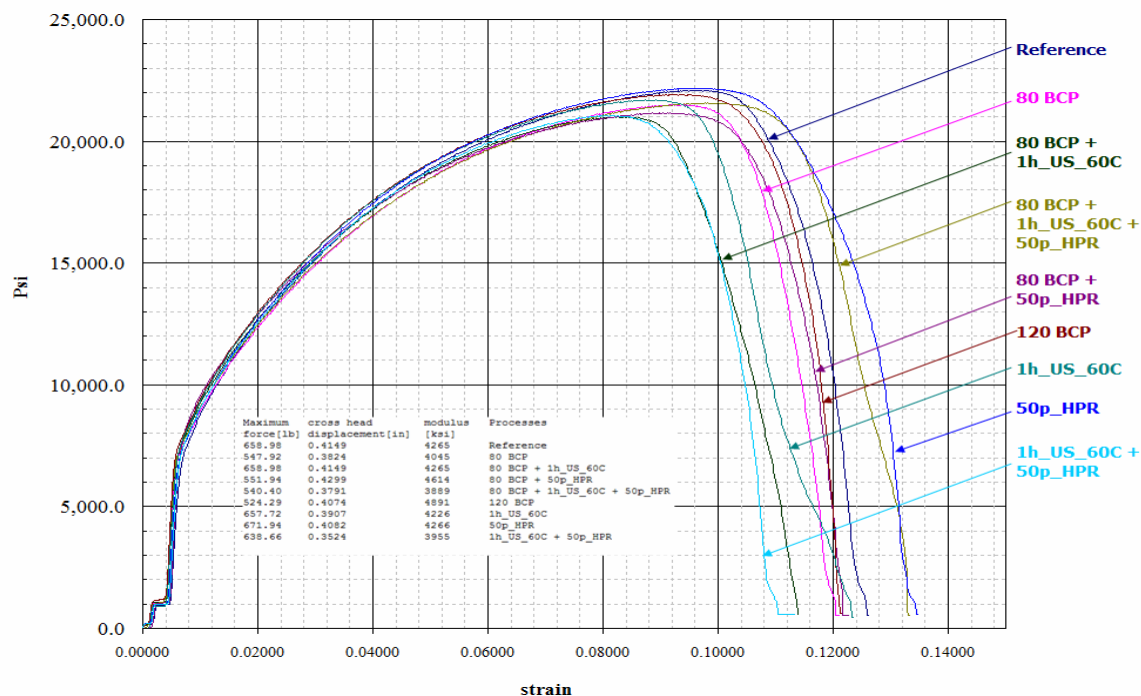
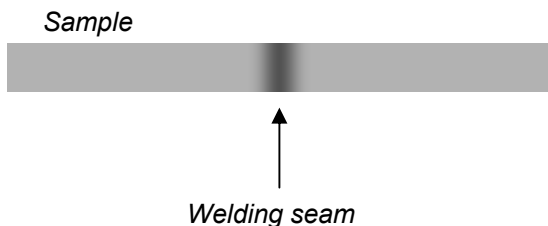
Possible developments (mid term)



- Hydrogen, oxygen embrittlement at low temperature
- Effect of welding
- Grain boundary strength,
- Crystal orientation/texture effects
- ...



Study of the mechanical behavior of welded Nb : note that the elongation is only 12-14 % (compare to bulk Nb ~ 30 %)

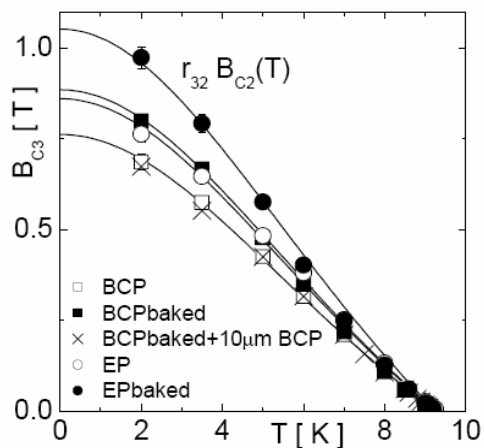
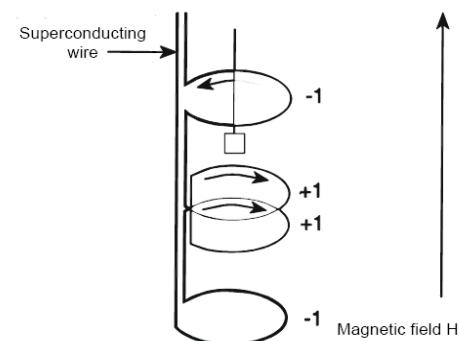
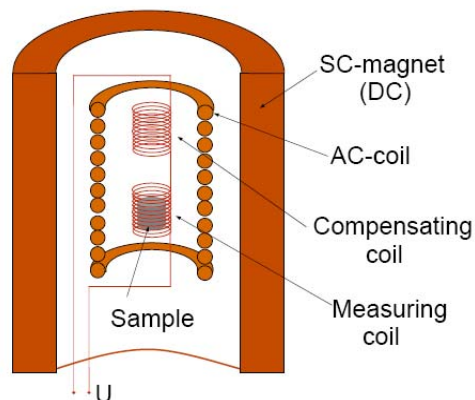
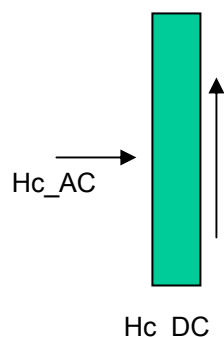




Monocrystal Nb program...

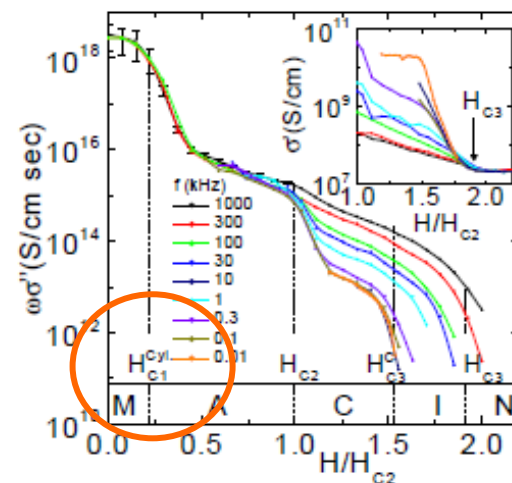
AC susceptibility, magnetization measurement

- 1st step: buy a commercial magnetometer for B_{C3} measurement/ or collabn
- It is the only technique sensitive enough to baking/surface processing !



[S. Casalbuoni et al, Hamburg]

- 2nd step : try to measure H_{C1} .
- ∃ very few information on H_{C1}



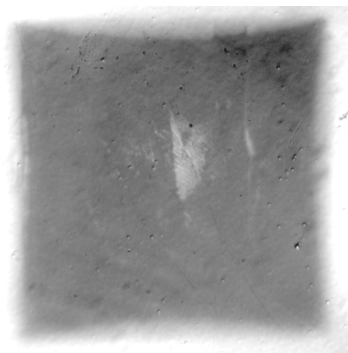
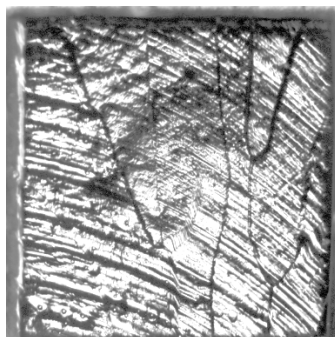


What is the problem with GB ?

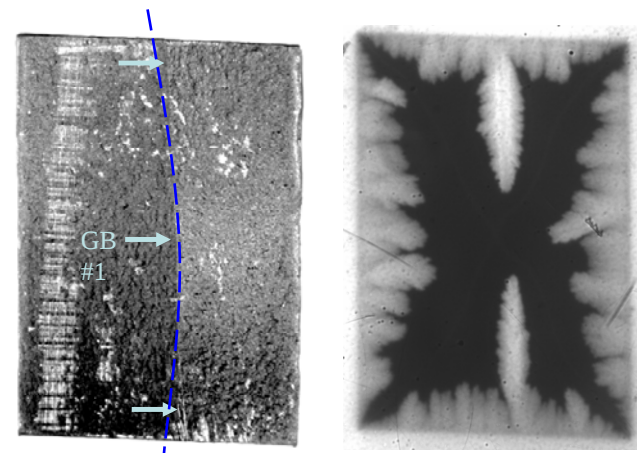
Morphological effect or depleted SC ?



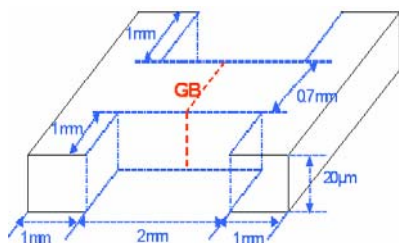
Flux penetration @ GB



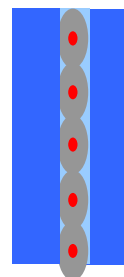
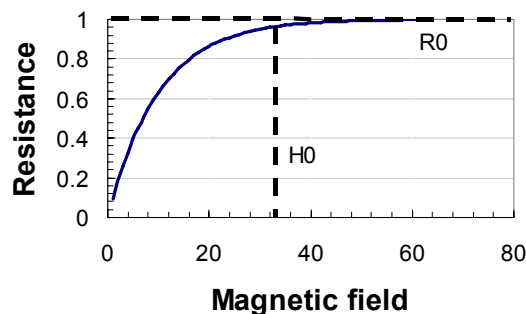
[A. Polyanskii et al, WU/FSU]



[P. Lee, next talk]



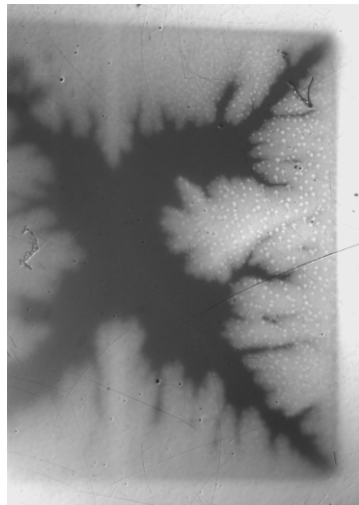
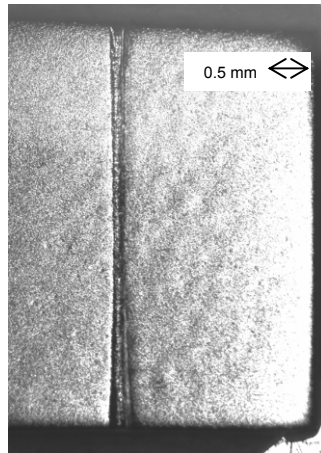
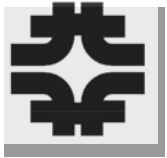
[Sung Hawn]



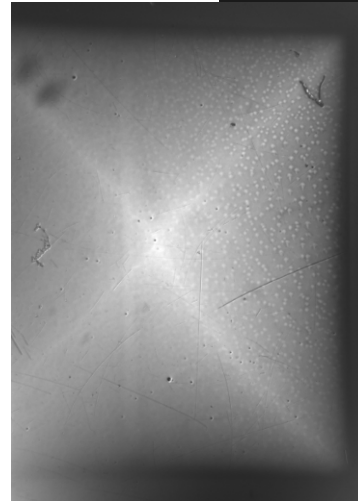
Saturation-field H_0 gives information on de-pairing J_d of SC GB



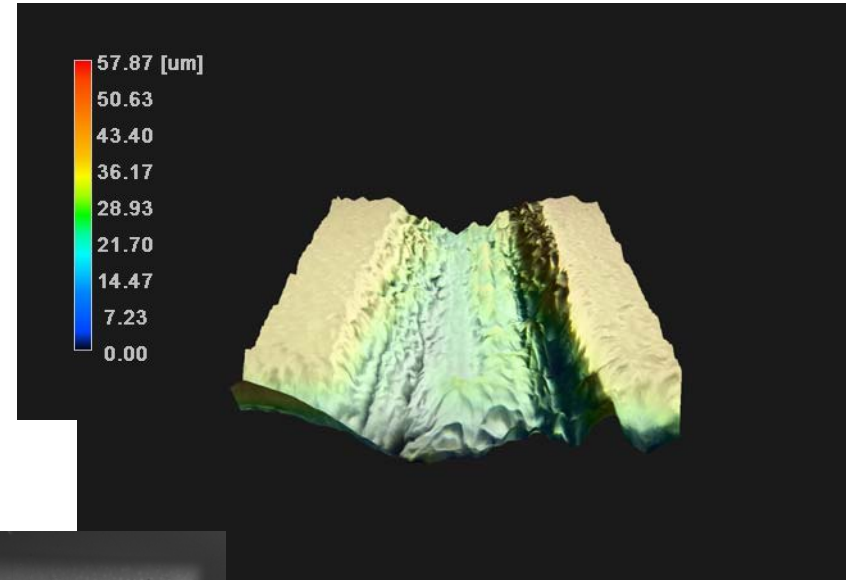
Single crystal with artificial defect (notch) on the surface



#52 ZFC H=40 mT T=7K



#62 Remn H=80 mT T=7K

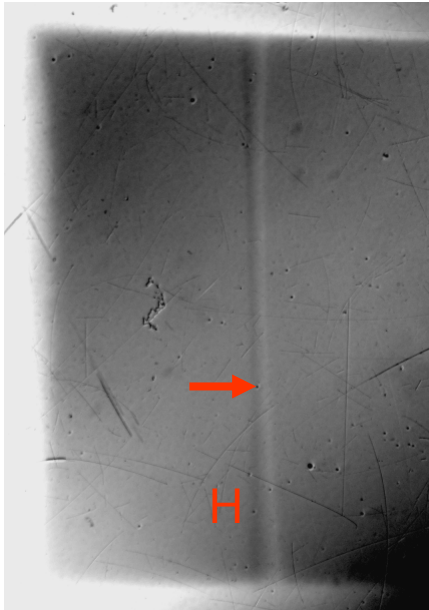
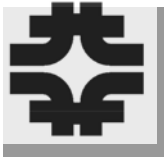


[A. Polyanskii et al, WU/FSU]

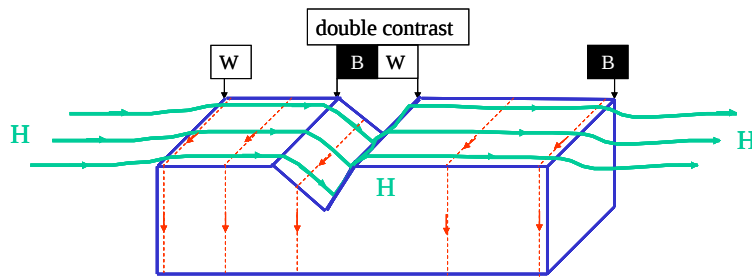
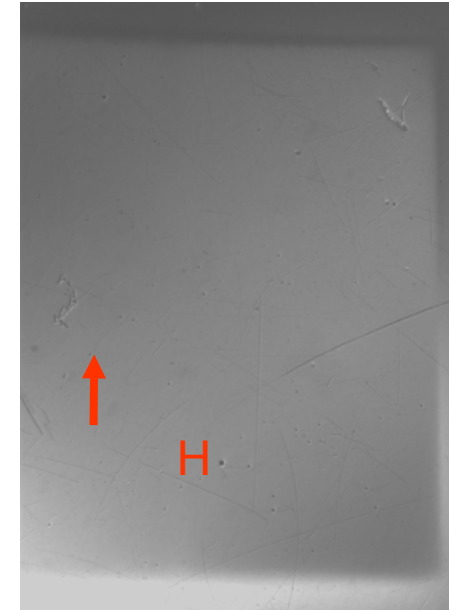
- $H \perp$ surface: notch has small impact on flux distribution even at higher T



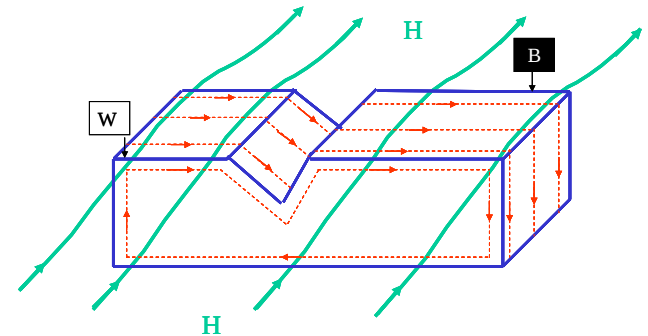
Single crystal with notch on the surface : $H \parallel$ surface



$T=5.6K$



MO contrast is double at the groove, when in-plane field perpendicular to groove



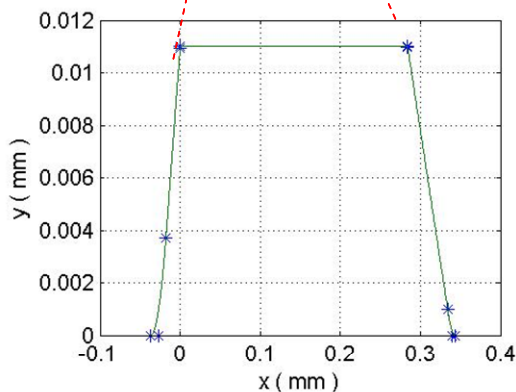
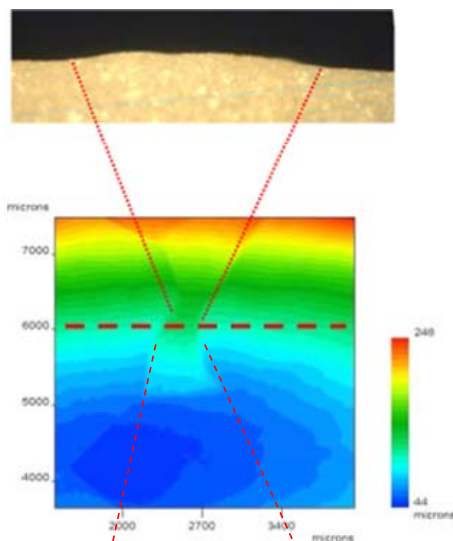
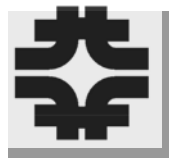
No MO contrast at the groove, when in-plane field parallel to groove

Morphological effect ... Roughness

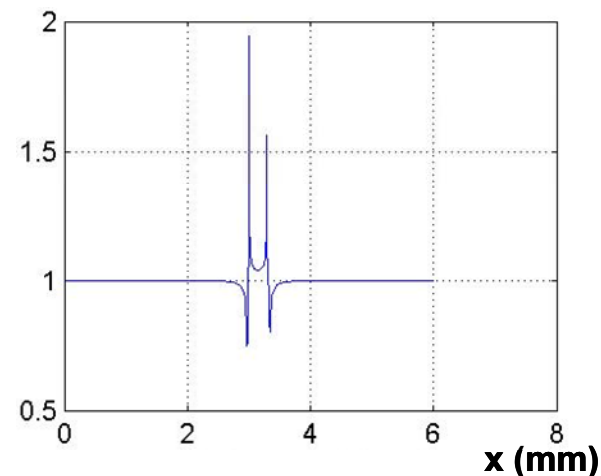


Working hypothesis: morphology => quench

- Steps perpendicular to H produce field enhancement
- It triggers quench
- This phenomena is different from the hot spots observed when $\exists$ Q-drop

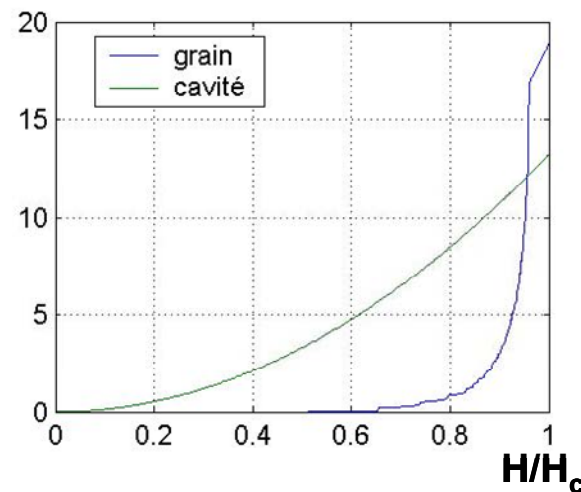


$H/\langle H \rangle$

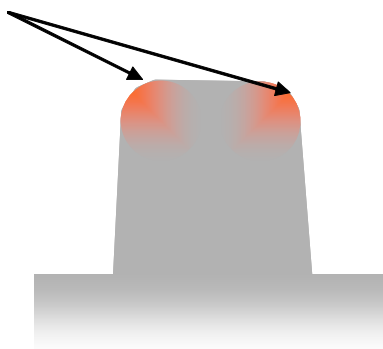


$P \text{ (W)}$

*Dissipated power
($R_s \sim 2m\Omega$)*



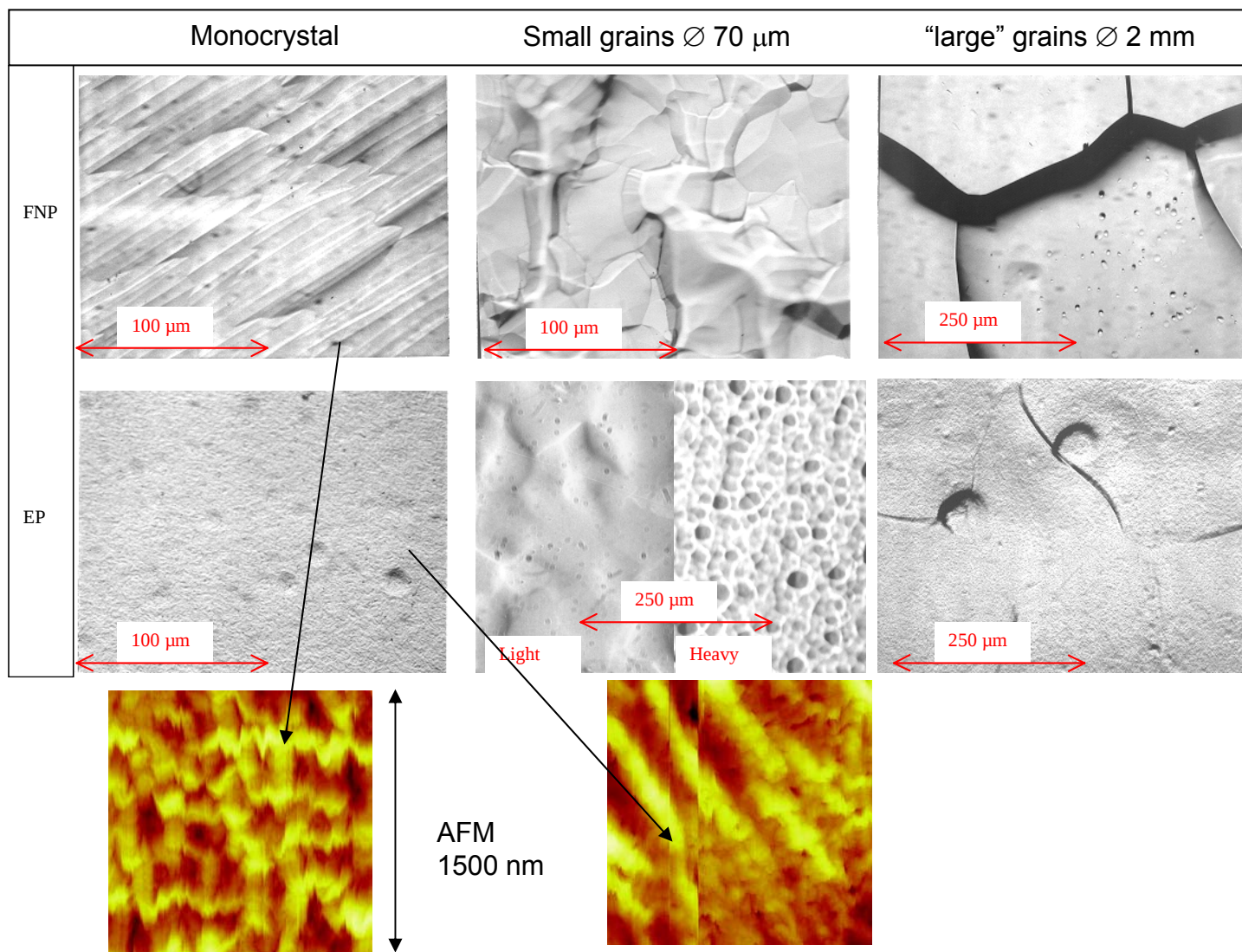
Normal conducting zones





Influence of GB on roughness

- Roughness depends on grain $\varnothing$





Roughness depends on observation scale

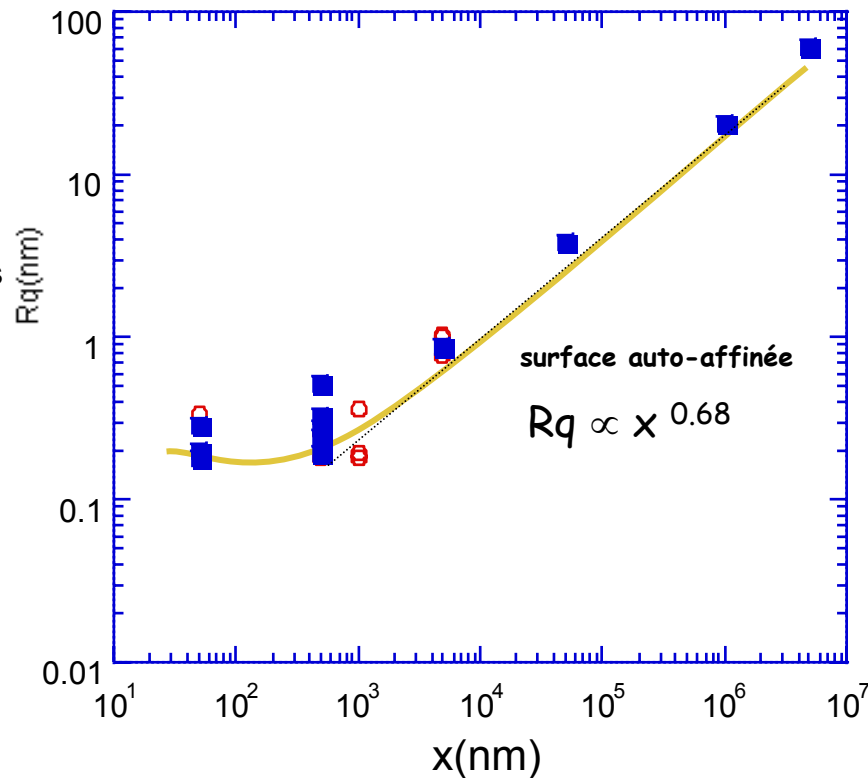
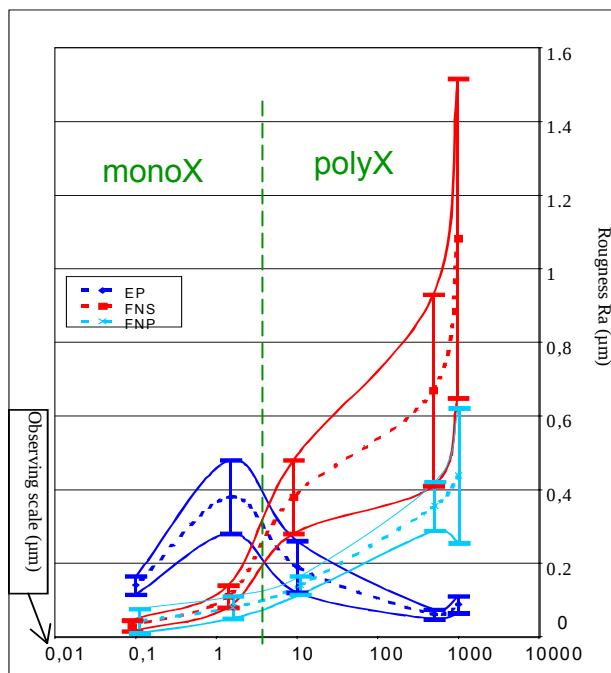
■ On Silicon (monoXstal)

[J. Amrit et al, Orsay]

“Most polished crystal surfaces, including silicon crystal surfaces, display a fractal behavior [6], that is, the root-mean-squared roughness height varies as

$$\sigma \approx bx^\alpha,$$

where b is a constant and α the roughness exponent.”

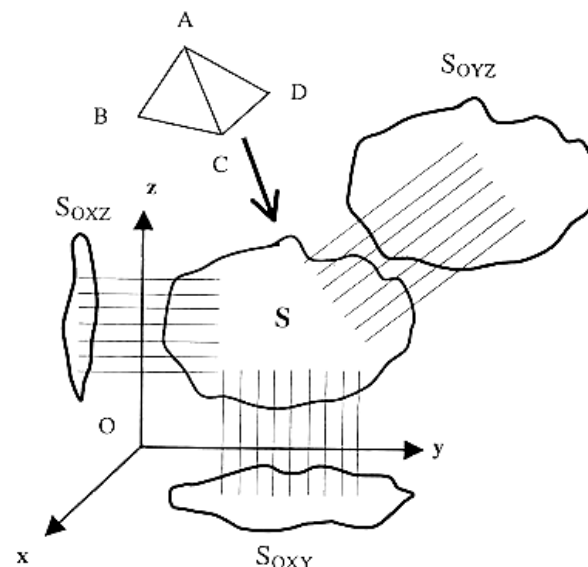
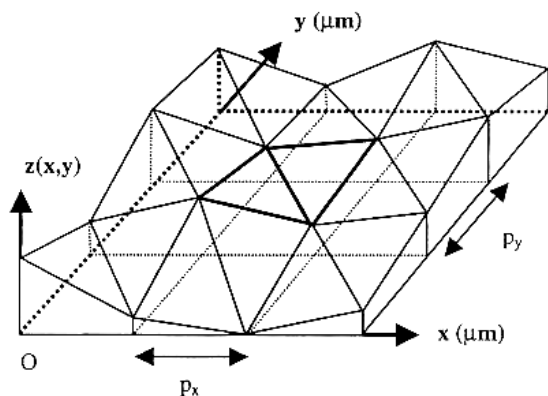
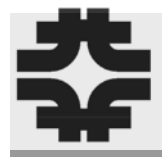


■ On Nb (mono/polyXstal)

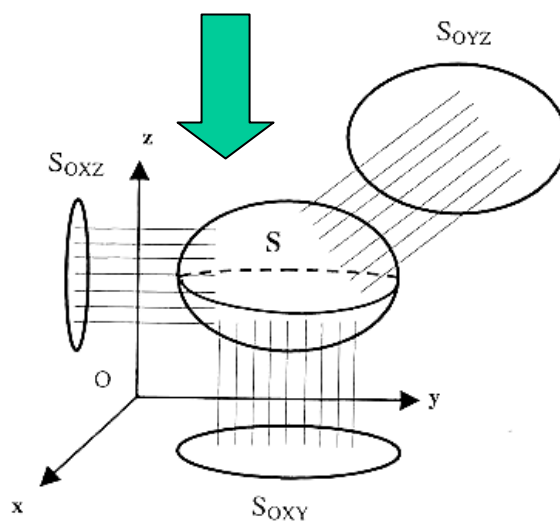
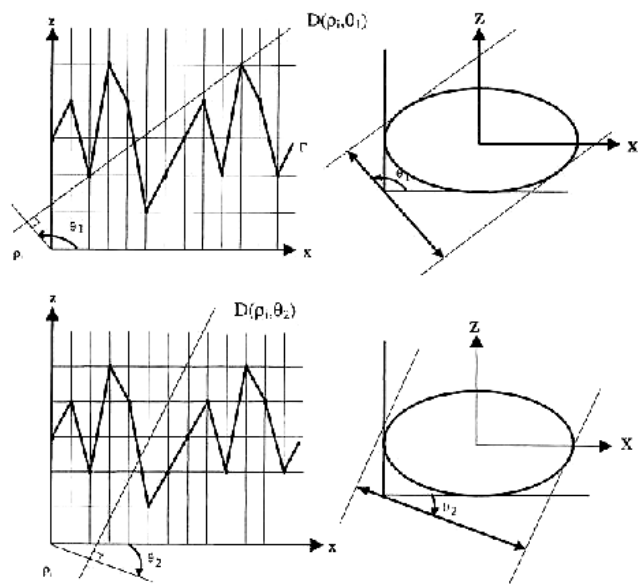




« conformal equivalent structure » concept

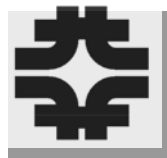


1. Decomposition of a sampled surface into elementary segments (mode) or elementary micro-triangles (3D mode).





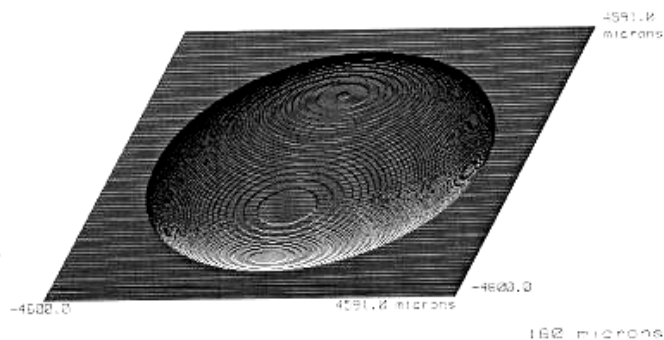
On Nb samples



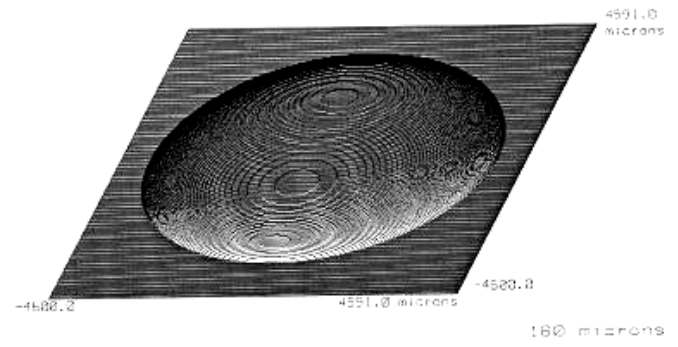
a) Annealed ~ 1 grain

b) not annealed ~ 15 grains

EP

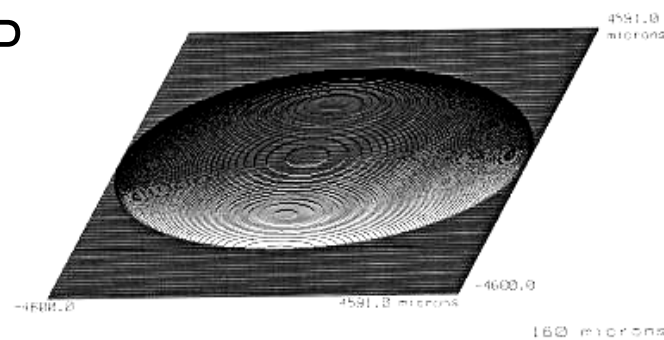


7R.A-EP recuit

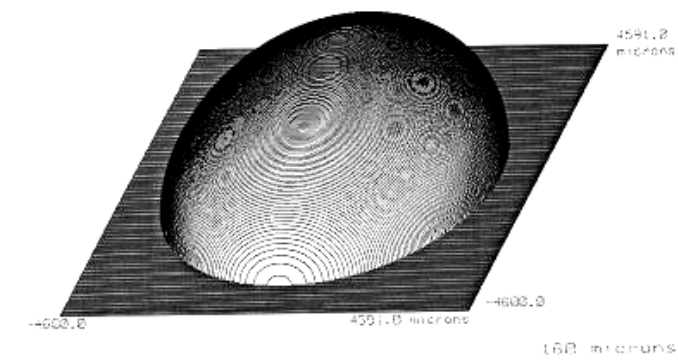


7B-EP non recuit

BCP



1R A-FNP recuit



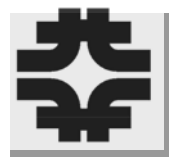
7F-FNP non recuit

a) Annealed material with grain $\varnothing \sim 1-2$ mm

b) Small grain material with $\varnothing \sim 70$ μ m



Grain boundaries and roughness



Scanned surface	Step size	Average grain #	Process	Ra	C	β
1 mm ²	1 μ m	1 ^{a)}	EP	0.69	9.3	
			BCP	2.9	12.1	
		~15 ^{b)}	EP	0.8	13	
			BCP	2.2	49	
85 mm ²	9 μ m	8-9 ^{a)}	EP	0.8	63.2	1.0135
			BCP	5	98	1.0283
		~ 1250 ^{b)}	EP	4.33	78.5	1.0182
			BCP	1.9	313	1.0651

a) Annealed material with grain $\varnothing \sim 1-2$ mm

b) Small grain material with $\varnothing \sim 70$ μ m

Parameter	out of welding seam	on welding seam
R _a (μ m)	6.1 $\pm$ 1.8	60.6 $\pm$ 23.4
c (μ m)	96.5 $\pm$ 3.6	354.3 $\pm$ 7.2

$$\beta \sim 1.4$$



Conclusion/ Proposal

Hypothesis:

- GB are harmful only because of BCP differential etching rate with orientation

- The field enhancement factor $\uparrow$ with $\uparrow \emptyset$ of grains

Then

- Only GB to $\perp$ H are dangerous

- Cavities with a GB // to the welding seem should be OK

- Less fabrication steps

- Delicate crystallographic alignment of the 2 half cells would not be necessary

- Let's discuss that at the next coffee break !

